

NPN SILICON PLANAR SWITCHING TRANSISTORS

2N2221 2N2222

C B E

TO-18 Metal Can Package

Switching and Linear Application DC and VHF Amplifier Applications

ABSOLUTE MAXIMUM RATINGS (Ta=25°C unless specified otherwise)

DESCRIPTION	SYMBOL	2N2221, 22	UNIT
Collector Emitter Voltage	V _{CEO}	30	V
Collector Base Voltage	V _{CBO}	60	V
Emitter Base Voltage	V_{EBO}	5	V
Collector Current Continuous	I _C	800	mA
Power Dissipation @Ta=25°C	P _D	500	mW
Derate Above 25°C		2.28	mW/ºC
Power Dissipation @ Tc=25°C	P _D	1.2	W
Derate Above 25°C		6.85	mW/ºC
Operating and Storage Junction	T _j , T _{stg}	-65 to +200	°C
Temperature Range			

ELECTRICAL CHARACTERISTICS (Ta=25°C unless specified otherwise)

DESCRIPTION	SYMBOL	TEST CONDITION	VALUE		
			MIN	MAX	UNIT
Collector Emitter Breakdown Voltage	BV_{CEO}	I _C =10mA,I _B =0	30		V
Collector Base Breakdown Voltage	BV_{CBO}	I _C =10μΑ.Ι _Ε =0	60		V
Emitter Base Breakdown Voltage	BV_{EBOf}	I _E =10μΑ, I _C =0	5		V
Collector Leakage Current	I _{CBO}	V_{CB} =50V, I _E =0		10	nA
		V _{CB} =50V, I _E =0		10	μA
		Ta=150 ° C			
Collector Emitter Saturation Voltage	V _{CE(Sat)} *	I _C =150mA,I _B =15mA		0.4	V
		I _C =500mA,I _B =50mA		1.6	V
Base Emitter Saturation Voltage	V _{BE(Sat)} *	I _C =150mA,I _B =15mA	0.6	1.3	V
		I _C =500mA,I _B =50mA		2.6	V

NPN SILICON PLANAR SWITCHING TRANSISTORS

2N2221 2N2222

C B E

TO-18 Metal Can Package

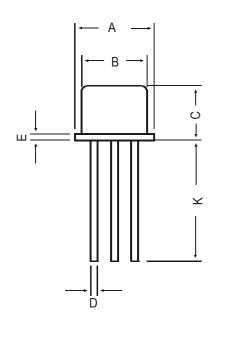
DESCRIPTION	SYMBOL TEST CONDITION		2221		2222		UNIT
		-	MIN	MAX	MIN	MAX	
DC Current Gain	h _{FE}	I _C =0.1mA,V _{CE} =10V*	20		35		
		I _C =1mA,V _{CE} =10V	25		50		
		I _C =10mA,V _{CE} =10V*	35		75		
		I _C =150mA,V _{CE} =1V*	20		50		
		I _C =150mA,V _{CE} =1V*	40	120	100	300	
		I _C =500mA,V _{CE} =10V*	20		30		
DYNAMIC CHARACTERISTICS							
Transition Frequency	f_{T}	I _C =20mA, V _{CE} =20V	250		250		MHz
		f=100MHz					
Output Capacitance	C _{ob}	V _{CB} =10V, I _E =0		8		8	pF
		f=100KHz					
Input Capacitance	C _{ib}	V _{FB} =0.5V, I _C =0		30		30	pF
		f=100kHz					·
SWITCHING CHARACTERISTICS							
Delay time	t _d					10	ns
	ŭ	I _c =150mA,IB1=15mA					
Rise time	t _r	V _{CC} =30V,V _{BE(off)} =0.5V				25	ns
Storage time	t _s					225	ns
U	5	I _c =150mA, IB1=15mA				-	-
Fall time	t _f	IB2=15mA, V _{CC} =30V				60	ns

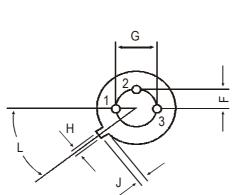
*Pulse Condition: Pulse Width \leq 300µs, Duty Cycle \leq 2%

2N2221 2N2222

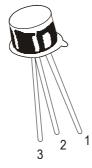
TO-18 Metal Can Package

TO-18 Metal Can Package





	DIM	MIN	MAX		
	А	5.24	5.84		
	В	4.52	4.97		
	С	4.31	5.33		
	D	0.40	0.53		
	Е	_	0.76		
All diminsions in mm.	F	_	1.27		
	G	_	2.97		
suc	Н	0.91	1.17		
nsic	J	0.71	1.21		
dimi	Κ	12.70	_		
All c	L	45 DEG			



PIN CONFIGURATION 1. EMITTER 2. BASE 3. COLLECTOR

Packing Detail

PACKAGE	STANDARD PACK		INNER CARTON BOX		OUTER CARTON BOX		
	Details	Net Weight/Qty	Size	Qty	Size	Qty	Gr Wt
T0-18	1K/polybag	350 gm/1K pcs	3" x 7.5" x 7.5"	5K	17" x 15" x 13.5"	80K	34 kgs

2N2221 2N2222

TO-18 Metal Can Package

Disclaimer

The product information and the selection guides facilitate selection of the CDIL's Discrete Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished in the Data Sheet and on the CDIL Web Site/CD is believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information. Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products are not designed for use in life saving/support appliances or systems. CDIL customers selling these products (either as individual Discrete Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and CDIL will not be responsible for any damages resulting from such sale(s).

CDIL strives for continuous improvement and reserves the right to change the specifications of its products without prior notice.



CDIL is a registered Trademark of Continental Device India Limited C-120 Naraina Industrial Area, New Delhi 110 028, India. Telephone + 91-11-579 6150 Fax + 91-11-579 9569, 579 5290 e-mail sales@cdil.com www.cdil.com